



Micro Commercial Components

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DTC144TKA

Features

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

Absolute Maximum Ratings

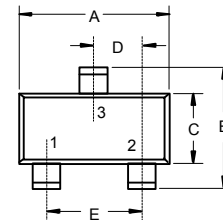
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base voltage	V_{EBO}	5	V
Collector Current-Continuous	I_C	100	mA
Collector Dissipation	P_C	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-55~150	°C

Electrical Characteristics

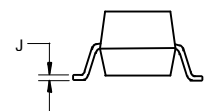
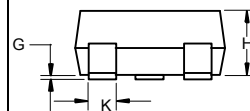
Sym	Parameter	Min	Typ	Max	Unit
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=50\mu A$, $I_E=0$)	50	---	---	V
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ($I_C=1mA$, $I_B=0$)	50	---	---	V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=50\mu A$, $I_C=0$)	5	---	---	V
I_{CBO}	Collector Cut-off Current ($V_{CB}=50V$, $I_E=0$)	---	---	0.5	μA
I_{EBO}	Emitter Cut-off Current ($V_{EB}=4V$, $I_C=0$)	---	---	0.5	μA
h_{FE}	DC Current Gain ($V_{CE}=5V$, $I_C=1mA$)	100	300	600	---
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=10mA$, $I_B=1mA$)	---	---	0.3	V
R_1	Input resistance	32.9	47	61.1	K Ω
f_T	Transition Frequency ($V_{CE}=10V$, $I_C=-5mA$, $f=100MHz$)	---	250	---	MHz

NPN Digital Transistor

SOT-23-3L

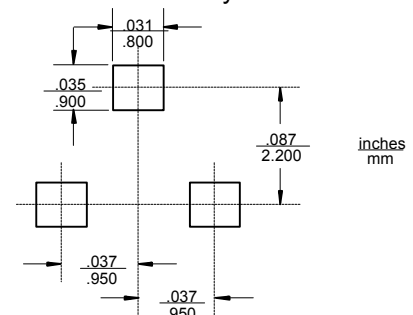


1. Base
2. Emitter
3. Collector



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.113	.117	2.87	2.97	
B	.108	.112	2.75	2.85	
C	.061	.065	1.55	1.65	
D	.036	.038	.925	.975	
E	.073	.077	1.85	1.95	
G	.0016	.0039	.04	.100	
H	.044	.049	1.12	1.25	
J	.006	.007	.14	.17	
K	.013	.015	.34	.37	

Suggested Solder Pad Layout



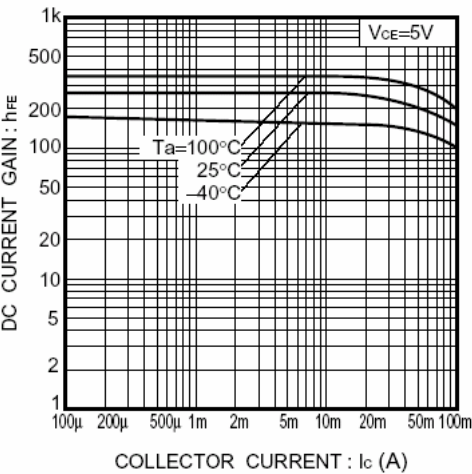


Fig.1 DC current gain vs. collector current

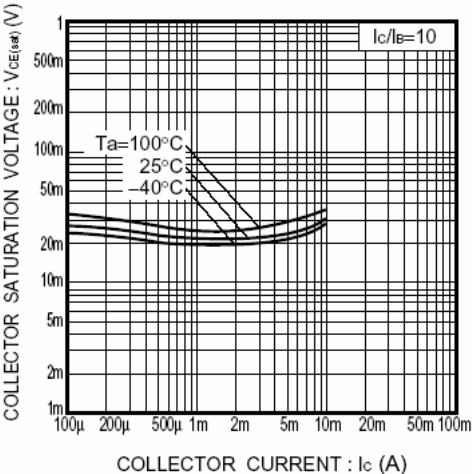
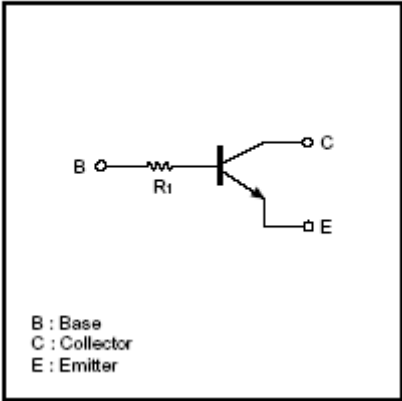


Fig.2 Collector-emitter saturation voltage vs. collector current

●Equivalent circuit



B : Base
C : Collector
E : Emitter